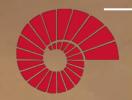
COMPUTER Systems &

gramming

Lecture #20 - The Memory Hierarchy



KOÇ UNIVERSITY

Aykut Erdem // Koç University // Fall 2021

Recap

- Floating Point
- Memory Layout
- Buffer Overflow

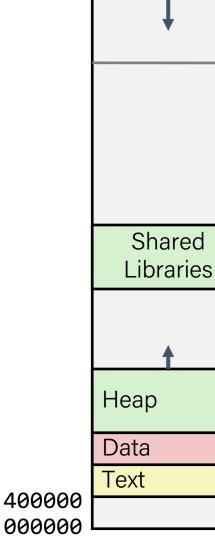
Recap: x86-64 Linux Memory Layout

not drawn to scale

8MB

Stack

- Stack
 - Runtime stack (8MB limit)
 - E. g., local variables
- Heap
 - Dynamically allocated as needed
 - When call malloc(), calloc(), new()
- Data
 - Statically allocated data
 - E.g., global vars, static vars, string constants
- Text / Shared Libraries
 - Executable machine instructions
 - Read-only



00007FFFFFFFFF

Hex Address

Recap: Memory Referencing Bug Example

```
typedef struct {
  int a[2];
  double d;
} struct_t;
double fun(int i) {
  volatile struct_t s;
  s.d = 3.14;
  s.a[i] = 1073741824; /* Possibly out of bounds */
  return s.d;
fun(0) \rightarrow 3.14
fun(1) \rightarrow 3.14
fun(2) \rightarrow 3.1399998664856
                                     Result is system specific
fun(3) \rightarrow 2.00000061035156
fun(4) \rightarrow 3.14
fun(6) → Segmentation fault
```

Recap: Buffer Overflows

- Buffer overflow bugs can allow remote machines to execute arbitrary code on victim machines
- Distressingly common in real programs
 - Programmers keep making the same mistakes 😕
 - Recent measures make these attacks much more difficult
- Examples across the decades
 - Original "Internet worm" (1988)
 - "IM wars" (1999)
 - Twilight hack on Wii (2000s)
 - ... and many, many more
- You will learn some of the tricks in Assignment 5
 - Hopefully to convince you to never leave such holes in your programs!!

COMP201 Topic 7: How does the memory system is organized as a hierarchy of different storage devices with unique capacities?

Plan for Today

- The memory abstraction
- Storage technologies and trends
- Locality of reference
- The memory hierarchy

Disclaimer: Slides for this lecture were borrowed from

- —Randal E. Bryant and David R. O'Hallaroni's CMU 15-213 class
- —Porter Jones' UW CSE 351 class

Lecture Plan

- The memory abstraction
- Storage technologies and trends
- Locality of reference
- The memory hierarchy

Writing & Reading Memory

Write

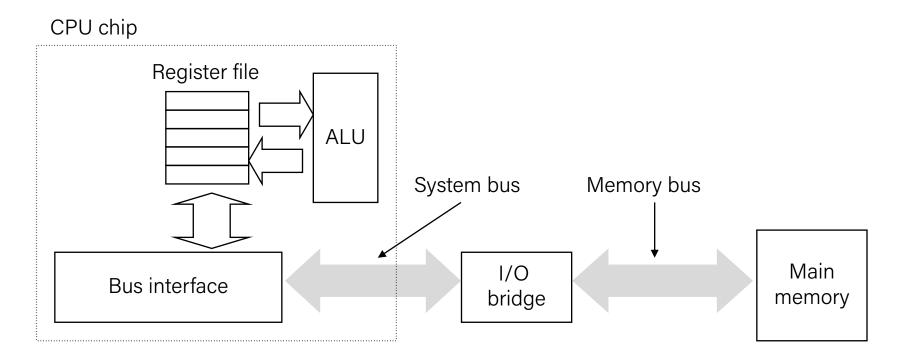
- -Transfer data from CPU to memory movq %rax, 8(%rsp)
- "Store" operation

Read

- -Transfer data from memory to CPU movq 8(%rsp), %rax
- "Load" operation

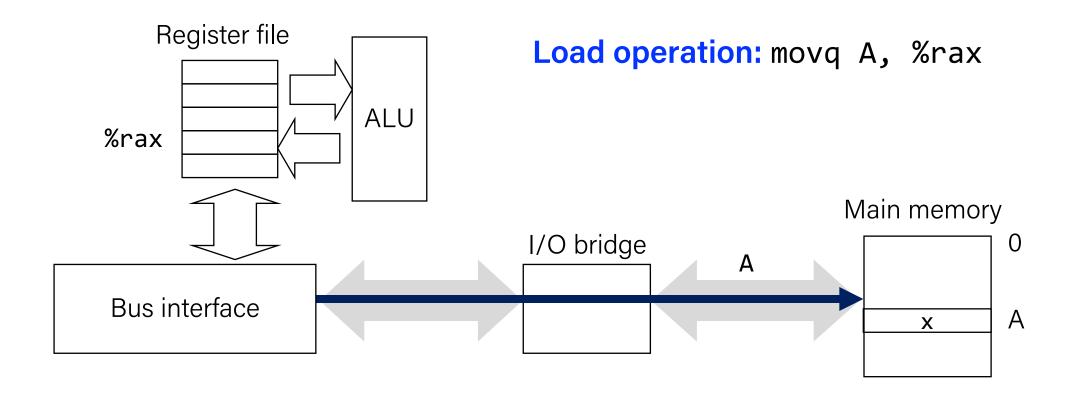
Traditional Bus Structure Connecting CPU and Memory

- A bus is a collection of parallel wires that carry address, data, and control signals.
- Buses are typically shared by multiple devices.



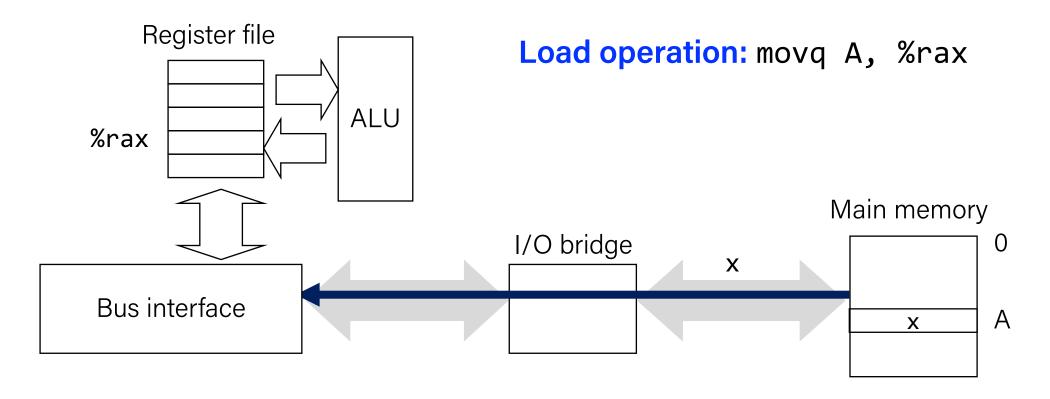
Memory Read Transaction (1)

• CPU places address A on the memory bus.



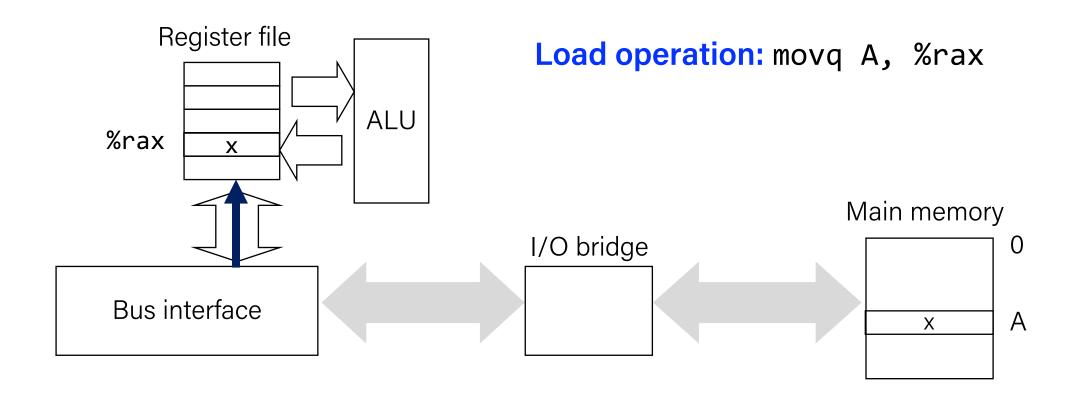
Memory Read Transaction (2)

• Main memory reads A from the memory bus, retrieves word x, and places it on the bus.



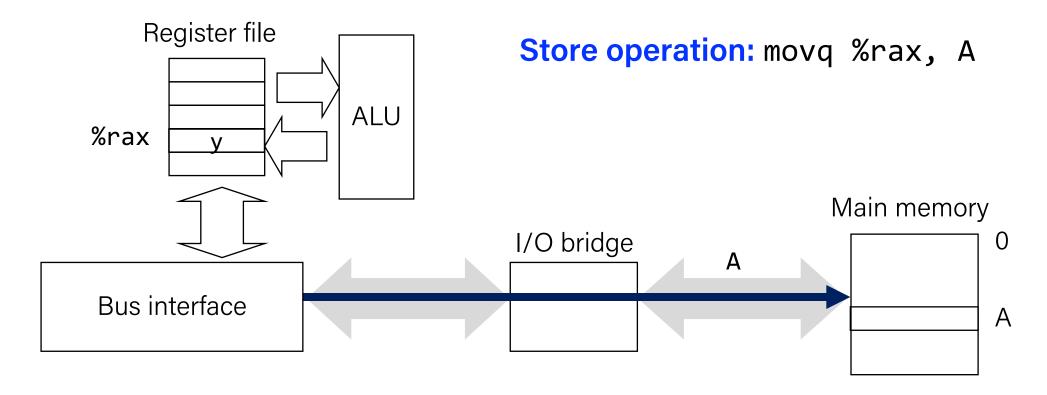
Memory Read Transaction (3)

• CPU read word x from the bus and copies it into register %rax.



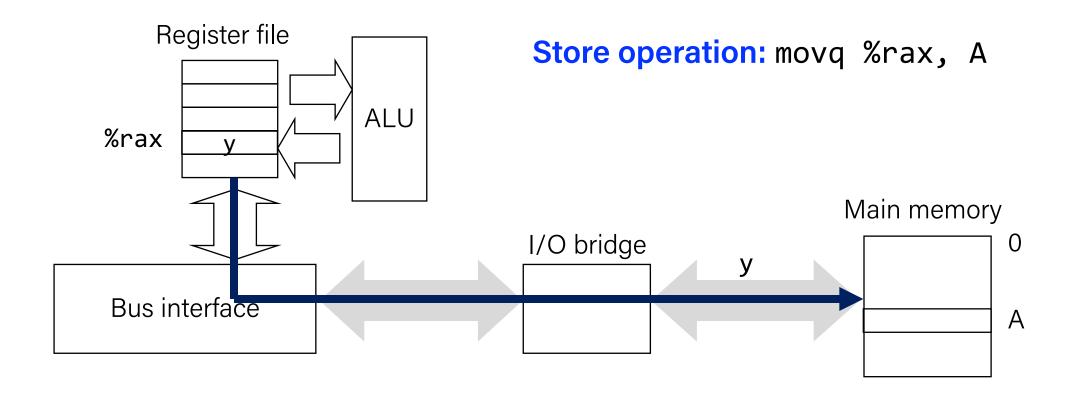
Memory Write Transaction (1)

• CPU places address A on bus. Main memory reads it and waits for the corresponding data word to arrive.



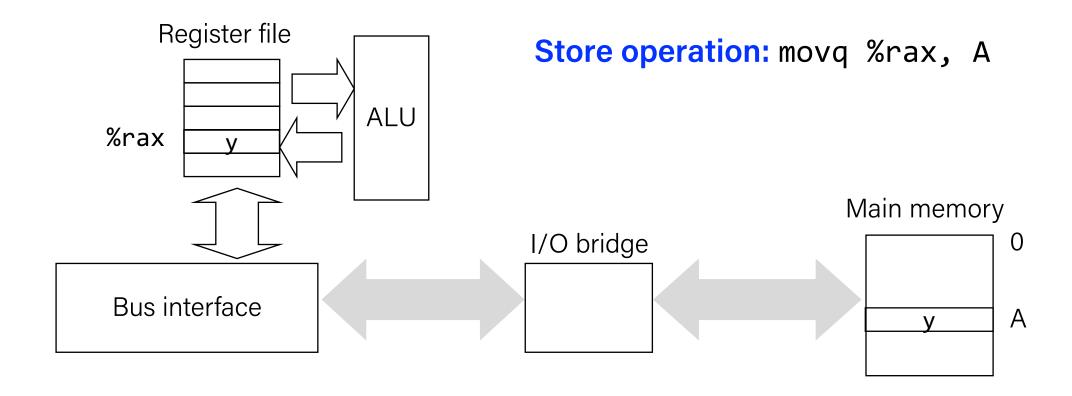
Memory Write Transaction (2)

CPU places data word y on the bus.



Memory Write Transaction (3)

Main memory reads data word y from the bus and stores it at address A.



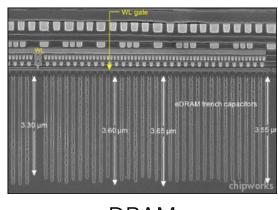
Lecture Plan

- The memory abstraction
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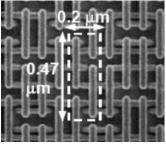
Random-Access Memory (RAM)

- Key features
 - RAM is traditionally packaged as a chip.
 - Basic storage unit is normally a cell (one bit per cell).
 - Multiple RAM chips form a memory.

- RAM comes in two varieties:
 - SRAM (Static RAM)
 - DRAM (Dynamic RAM)



DRAM



SRAM

SRAM vs DRAM Summary

	Trans. per bit	Access time	Needs refresh?	Need EDC?	Cost	Applications
SRAM	4 or 6	1X	No	Maybe	100X	Cache memories
DRAM	1	10X	Yes	Yes	1X	Main memories, frame buffers

EDC: Error detection and correction

Trends

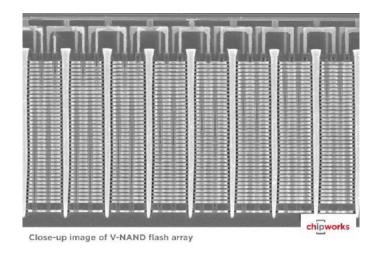
- SRAM scales with semiconductor technology
 - Reaching its limits
- DRAM scaling limited by need for minimum capacitance
 - Aspect ratio limits how deep can make capacitor
 - Also reaching its limits

Enhanced DRAMs

- Operation of DRAM cell has not changed since its invention
 - Commercialized by Intel in 1970.
- DRAM cores with better interface logic and faster I/O:
 - Synchronous DRAM (SDRAM)
 - Uses a conventional clock signal instead of asynchronous control
 - Double data-rate synchronous DRAM (DDR SDRAM)
 - Double edge clocking sends two bits per cycle per pin
 - Different types distinguished by size of small prefetch buffer:
 - DDR (2 bits), DDR2 (4 bits), DDR3 (8 bits), DDR4 (16 bits)
 - By 2010, standard for most server and desktop systems
 - Intel Core i7 supports DDR3 and DDR4 SDRAM

Storage Technologies

Nonvolatile (Flash) Memory



- Store as persistent charge
- Implemented with 3-D structure
 - 100+ levels of cells
 - 3 bits data per cell

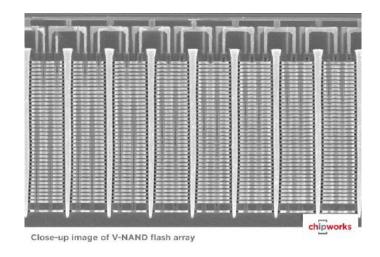
Magnetic Disks



- Store on magnetic medium
- Electromechanical access

Storage Technologies

Nonvolatile (Flash) Memory



- Store as persistent charge
- Implemented with 3-D structure
 - 100+ levels of cells
 - 3 bits data per cell

Magnetic Disks



- Store on magnetic medium
- Electromechanical access

Nonvolatile Memories

DRAM and SRAM are volatile memories

Lose information if powered off.

Nonvolatile memories retain value even if powered off

- Read-only memory (ROM): programmed during production
- Electrically eraseable PROM (EEPROM): electronic erase capability
- Flash memory: EEPROMs with partial (block-level) erase capability
 - Wears out after about 100,000 erasings
- 3D XPoint (Intel Optane) & emerging NVMs
 - New materials

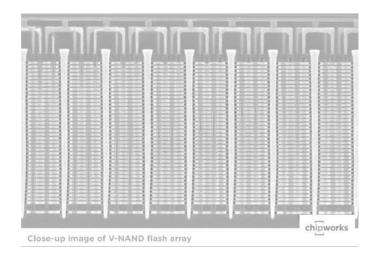


Uses for Nonvolatile Memories

- Firmware programs stored in a ROM (BIOS, controllers for disks, network cards, graphics accelerators, security subsystems,...)
- Solid state disks (replace rotating disks in thumb drives, smart phones, mp3 players, tablets, laptops,...)
- Disk caches

Storage Technologies

Nonvolatile (Flash) Memory



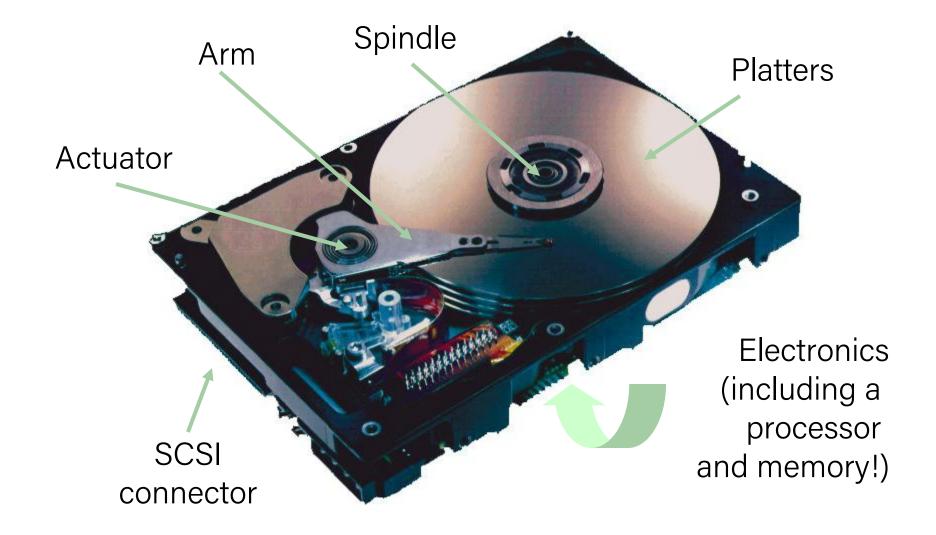
- Store as persistent charge
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 - 100+ levels of cells
 - 3 bits data per cell

Magnetic Disks



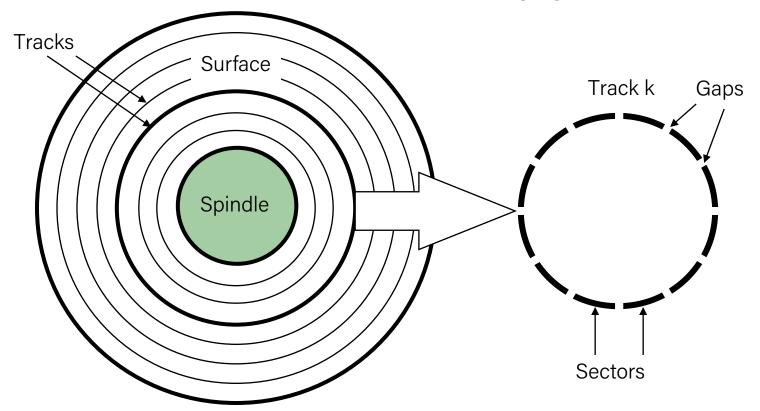
- Store on magnetic medium
- Electromechanical access

What's Inside A Disk Drive?



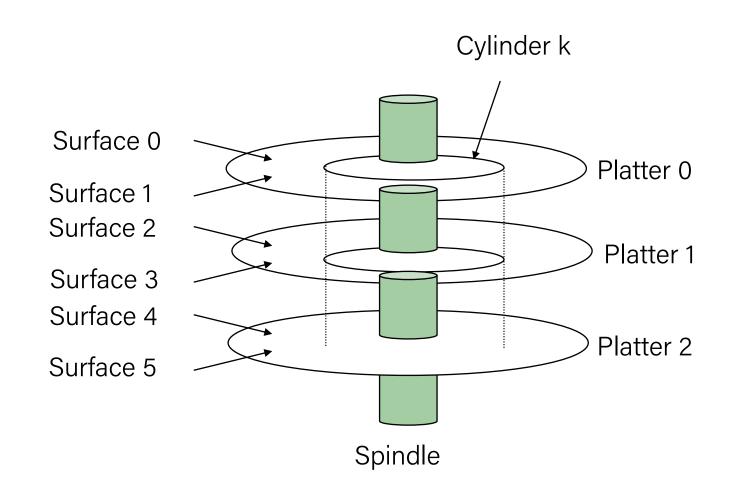
Disk Geometry

- Disks consist of **platters**, each with two **surfaces**.
- Each surface consists of concentric rings called tracks.
- Each track consists of sectors separated by gaps.



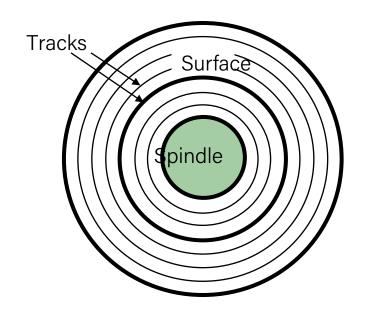
Disk Geometry (Muliple-Platter View)

• Aligned tracks form a cylinder.



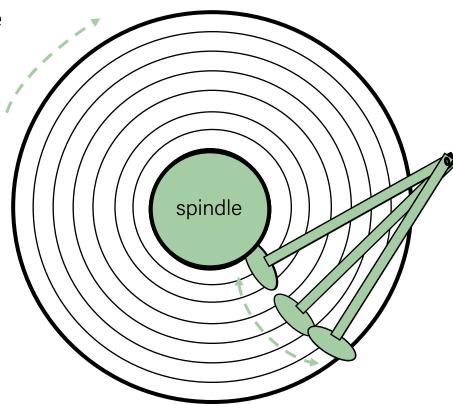
Disk Capacity

- Capacity: maximum number of bits that can be stored.
 - Vendors express capacity in units of gigabytes (GB) or terabytes (TB), where $1 \text{ GB} = 10^9 \text{ bytes}$ and $1 \text{ GB} = 10^{12} \text{ bytes}$.
- Capacity is determined by these technology factors:
 - Recording density (bits/in): number of bits that can be squeezed into a 1-inch segment of a track.
 - Track density (tracks/in): number of tracks that can be squeezed into a 1-inch radial segment.
 - Areal density (bits/in2): product of recording and track density.



Disk Operation (Single-Platter View)

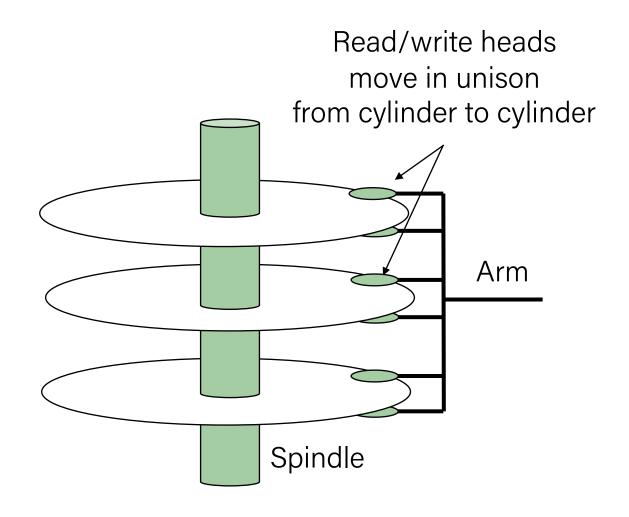
The disk surface spins at a fixed rotational rate



The read/write **head** is attached to the end of the **arm** and flies over the disk surface on a thin cushion of air.

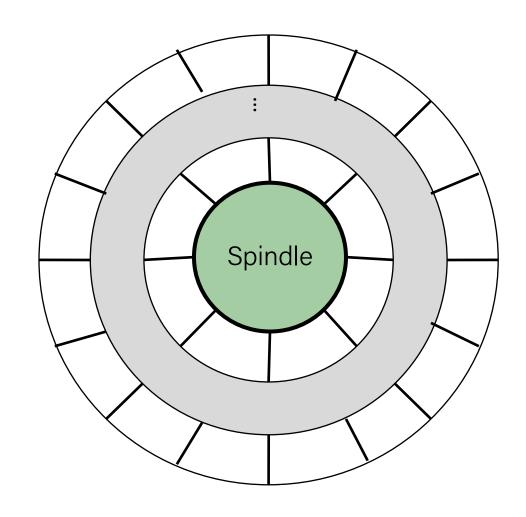
By moving radially, the arm can position the read/write head over any track.

Disk Operation (Multi-Platter View)



Recording zones

- Modern disks partition tracks into disjoint subsets called recording zones
 - Each track in a zone has the same number of sectors, determined by the circumference of innermost track.
 - Each zone has a different number of sectors/track, outer zones have more sectors/track than inner zones.
 - So we use average number of sectors/track when computing capacity.



Computing Disk Capacity

```
Capacity = (# bytes/sector) × (avg. # sectors/track) × (# tracks/surface) × (# surfaces/platter) × (# platters/disk)
```

Example:

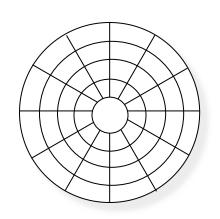
- 512 bytes/sector
- 300 sectors/track (on average)
- 20,000 tracks/surface
- 2 surfaces/platter
- 5 platters/disk

```
Capacity = 512 \times 300 \times 20000 \times 2 \times 5
= 30,720,000,000
= 30.72 GB
```

Logical Disk Blocks

- Modern disks present a simpler abstract view of the complex sector geometry:
 - The set of available sectors is modeled as a sequence of b-sized **logical blocks** (0, 1, 2, ...)
- Mapping between logical blocks and actual (physical) sectors
 - Maintained by hardware/firmware device called disk controller.
 - Converts requests for logical blocks into (surface, track, sector) triples.
- Allows controller to set aside spare cylinders for each zone.
 - Accounts for the difference in "formatted capacity" and "maximum capacity".

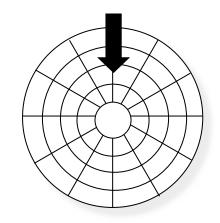
Disk Structure - top view of single platter



Surface organized into tracks

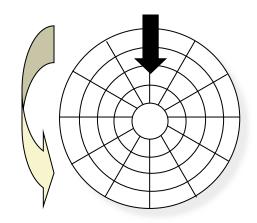
Tracks divided into sectors

Disk Access

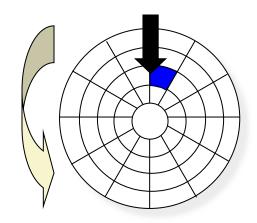


Head in position above a track

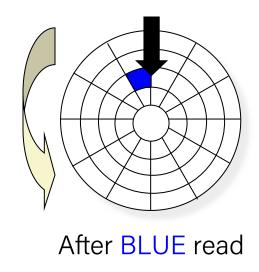
Disk Access



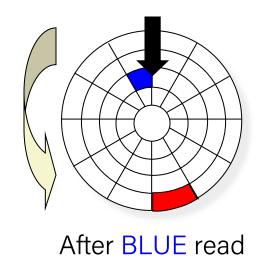
Rotation is counter-clockwise



About to read blue sector

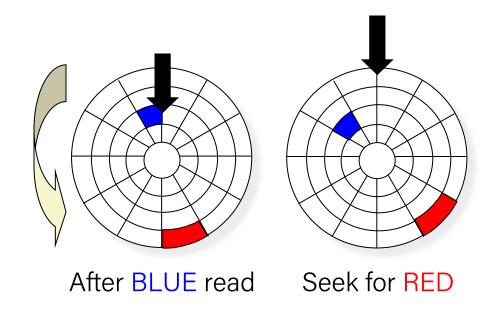


After reading blue sector



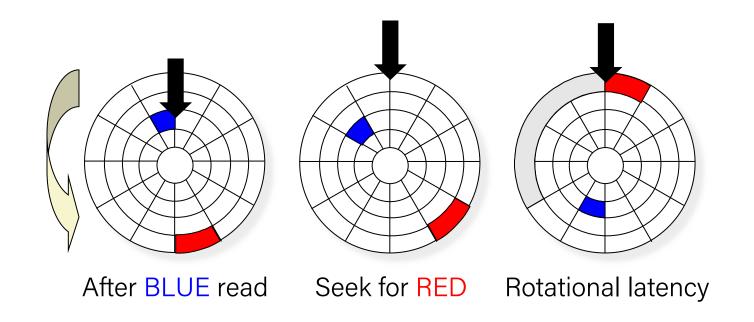
Red request scheduled next

Disk Access – Seek

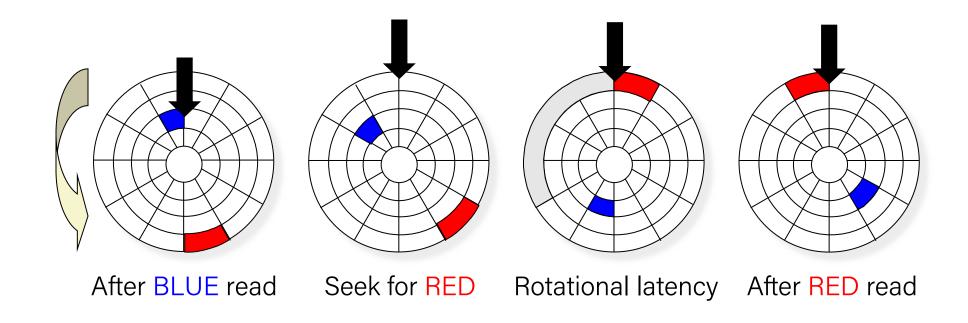


Seek to red's track

Disk Access - Rotational Latency

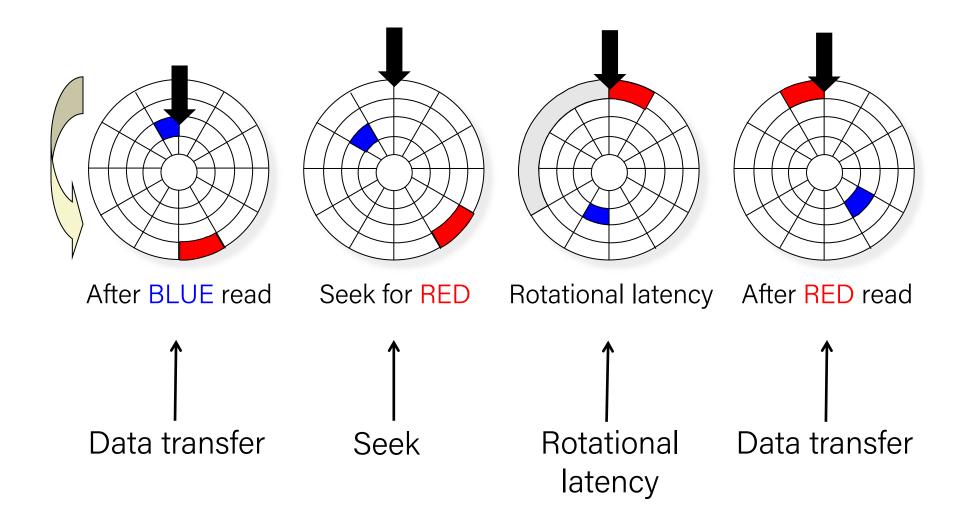


Wait for red sector to rotate around



Complete read of red

Disk Access - Service Time Components



Disk Access Time

- Average time to access some target sector approximated by:
 - Taccess = Tavg seek + Tavg rotation + Tavg transfer
- Seek time (Tavg seek)
 - Time to position heads over cylinder containing target sector.
 - Typical Tavg seek is 3—9 ms
- Rotational latency (Tavg rotation)
 - Time waiting for first bit of target sector to pass under r/w head.
 - Tavg rotation = $1/2 \times 1/RPMs \times 60 sec/1 min$
 - Typical Tavg rotation = 7200 RPMs
- Transfer time (Tavg transfer)
 - Time to read the bits in the target sector.
 - Tavg transfer = $1/RPM \times 1/(avg \# sectors/track) \times 60 secs/1 min.$

Disk Access Time Example

Given:

- Rotational rate = 7,200 RPM
- Average seek time = 9 ms.
- Avg # sectors/track = 400.

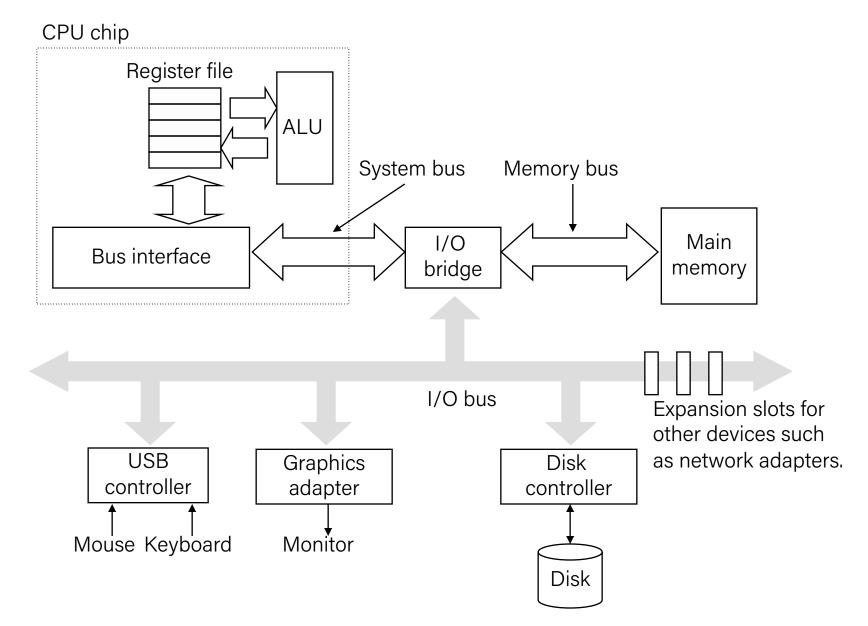
Derived:

- Tavg rotation = $1/2 \times (60 \text{ secs}/7200 \text{ RPM}) \times 1000 \text{ ms/sec} = 4 \text{ ms.}$
- Tavg transfer = $60/7200 \text{ RPM} \times 1/400 \text{ secs/track} \times 1000 \text{ ms/sec} = 0.02 \text{ ms}$
- Taccess = 9 ms + 4 ms + 0.02 ms

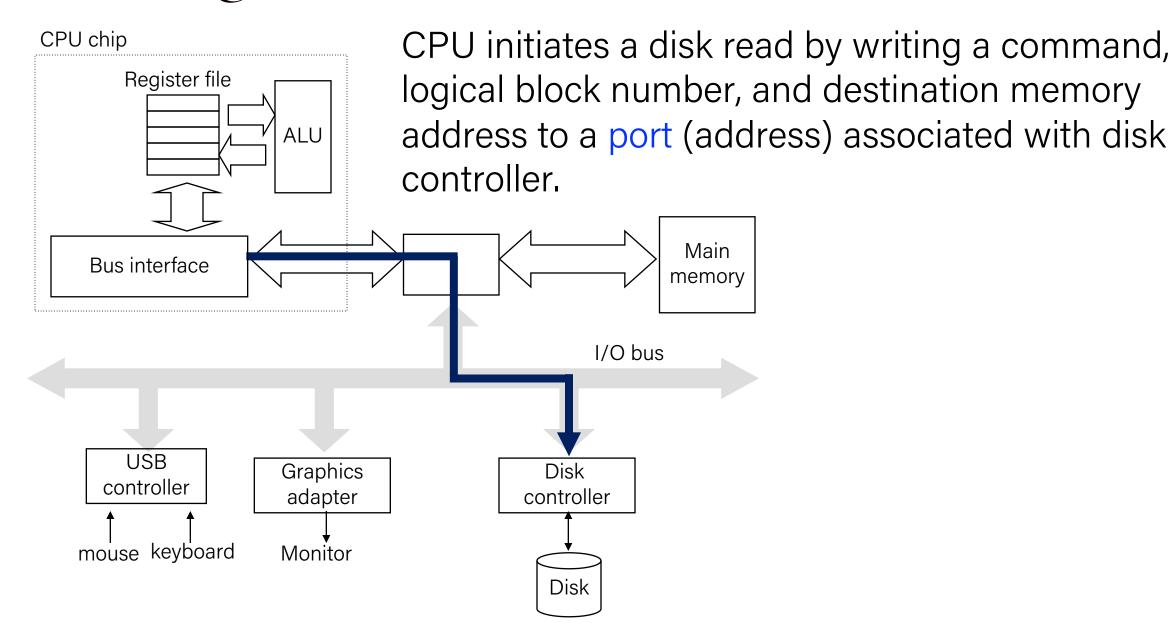
Important points:

- Access time dominated by seek time and rotational latency.
- First bit in a sector is the most expensive, the rest are free.
- SRAM access time is about 4 ns/doubleword, DRAM about 60 ns
 - Disk is about 40,000 times slower than SRAM,
 - 2,500 times slower than DRAM.

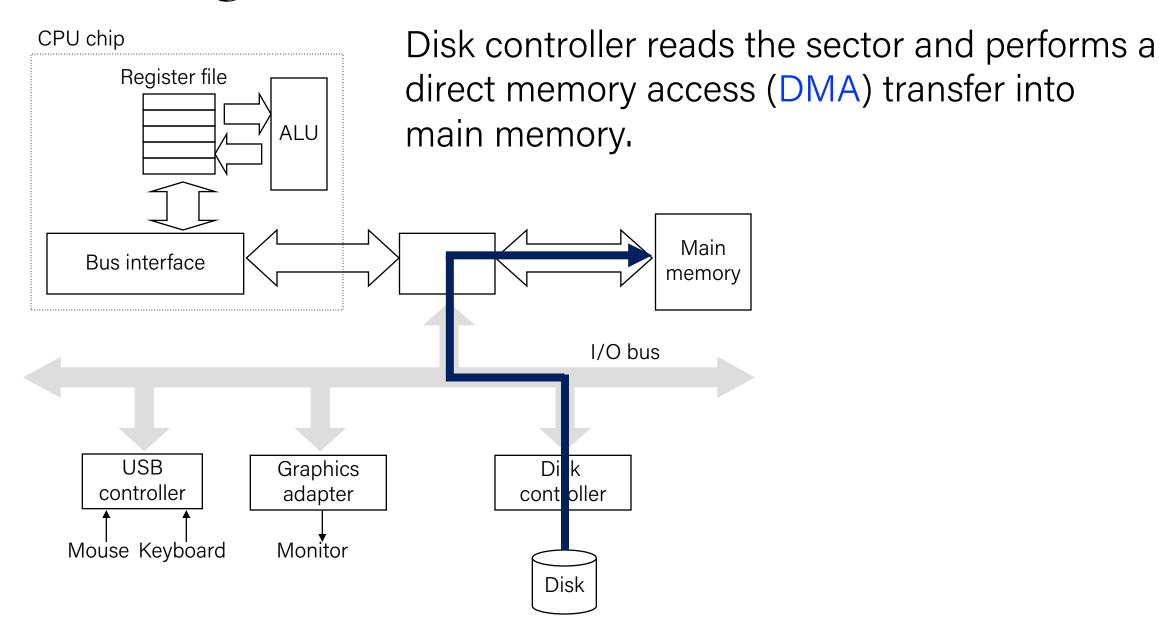
I/O Bus



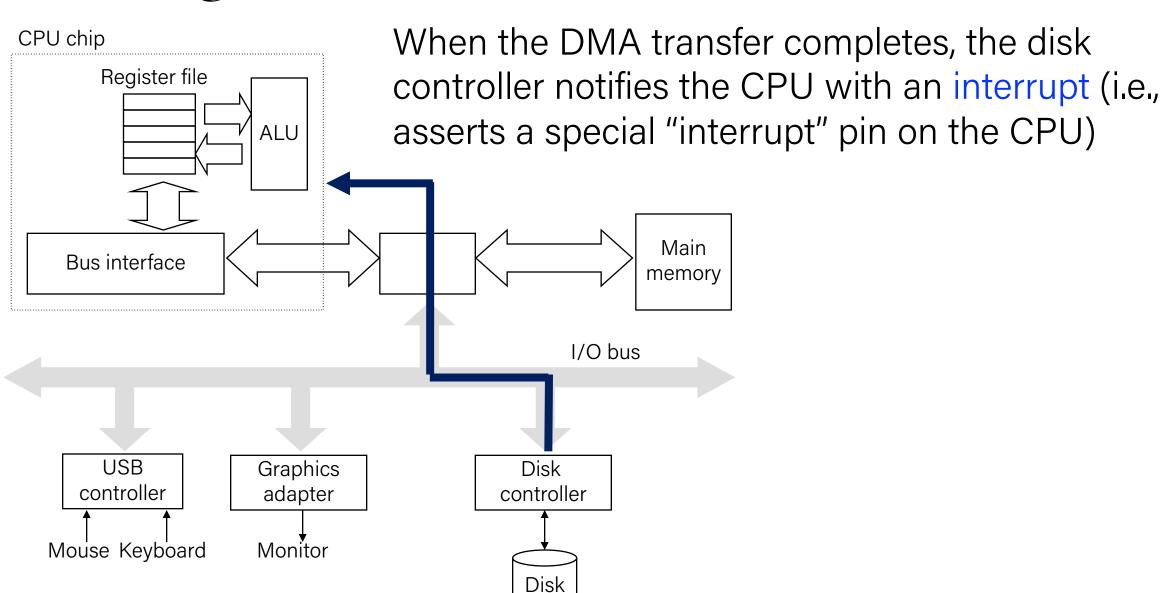
Reading a Disk Sector (1)



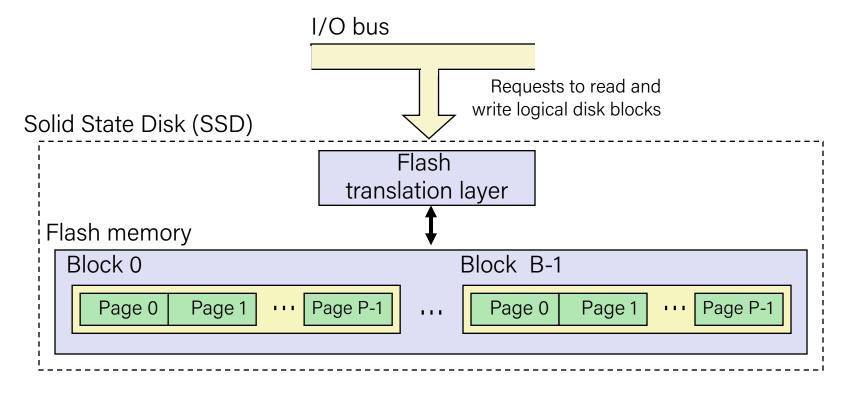
Reading a Disk Sector (2)



Reading a Disk Sector (3)



Solid State Disks (SSDs)



- Pages: 512KB to 4KB, Blocks: 32 to 128 pages
- Data read/written in units of pages.
- Page can be written only after its block has been erased
- A block wears out after about 100,000 repeated writes.

SSD Performance Characteristics

Benchmark of Samsung 940 EVO Plus

Sequential read tput 2,126 MB/s Sequential write tput 1,880 MB/s Random read tput 140 MB/s Random write tput 59 MB/s

https://ssd.userbenchmark.com/SpeedTest/711305/Samsung-SSD-970-EVO-Plus-250GB

- Sequential access faster than random access
 - Common theme in the memory hierarchy
- Random writes are somewhat slower
 - Erasing a block takes a long time (~1 ms)
 - Modifying a block page requires all other pages to be copied to new block
 - Flash translation layer allows accumulating series of small writes before doing block write.

SSD Tradeoffs vs Rotating Disks

Advantages

No moving parts → faster, less power, more rugged

Disadvantages

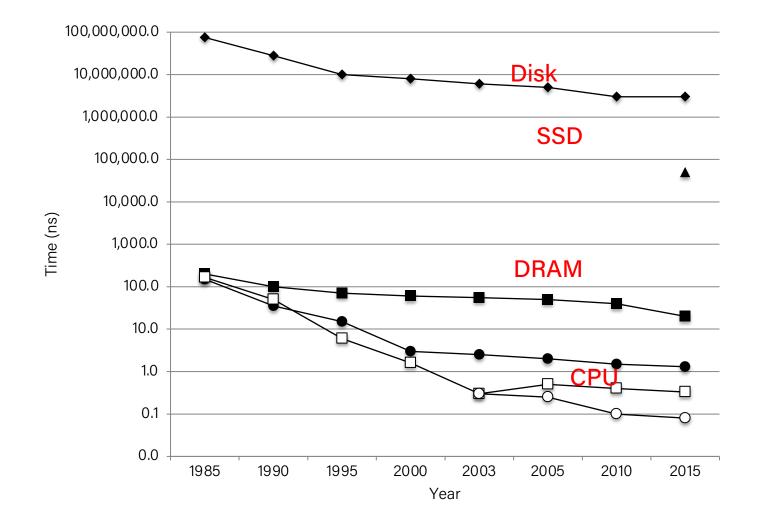
- Have the potential to wear out
 - Mitigated by "wear leveling logic" in flash translation layer
 - E.g. Samsung 940 EVO Plus guarantees 600 writes/byte of writes before they wear out
 - Controller migrates data to minimize wear level
- In 2019, about 4 times more expensive per byte
 - And, relative cost will keep dropping

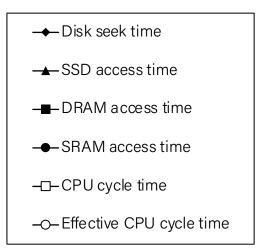
Applications

- MP3 players, smart phones, laptops
- Beginning to appear in desktops and servers

The CPU-Memory Gap

The gap widens between DRAM, disk, and CPU speeds.





Locality to the Rescue!

• The key to bridging this CPU-Memory gap is a fundamental property of computer programs known as locality

Lecture Plan

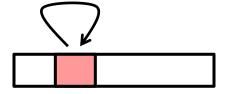
- The memory abstraction
- Storage technologies and trends
- Locality of reference
- The memory hierarchy

Locality

 Principle of Locality: Programs tend to use data and instructions with addresses near or equal to those they have used recently

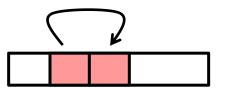
Temporal locality:

 Recently referenced items are likely to be referenced again in the near future



Spatial locality:

Items with nearby addresses tend
 to be referenced close together in time



Locality Example

```
sum = 0;
for (i = 0; i < n; i++)
   sum += a[i];
return sum;</pre>
```

Data references

 Reference array elements in succession (stride-1 reference pattern).

Spatial locality

- Reference variable sum each iteration.

Temporal locality

Instruction references

- Reference instructions in sequence.
- Cycle through loop repeatedly.

Spatial locality

Temporal locality

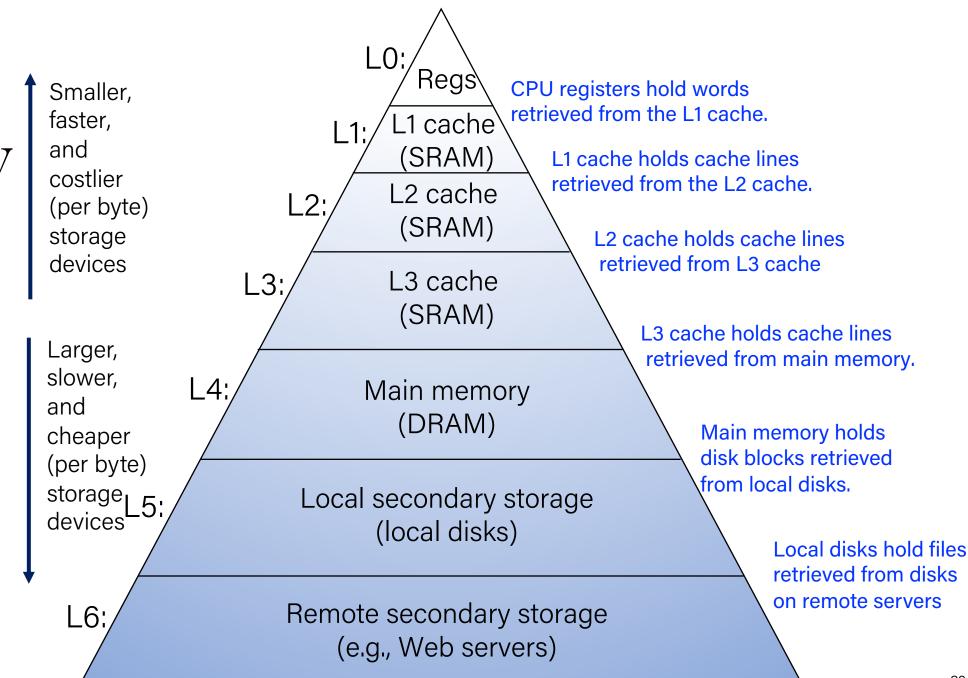
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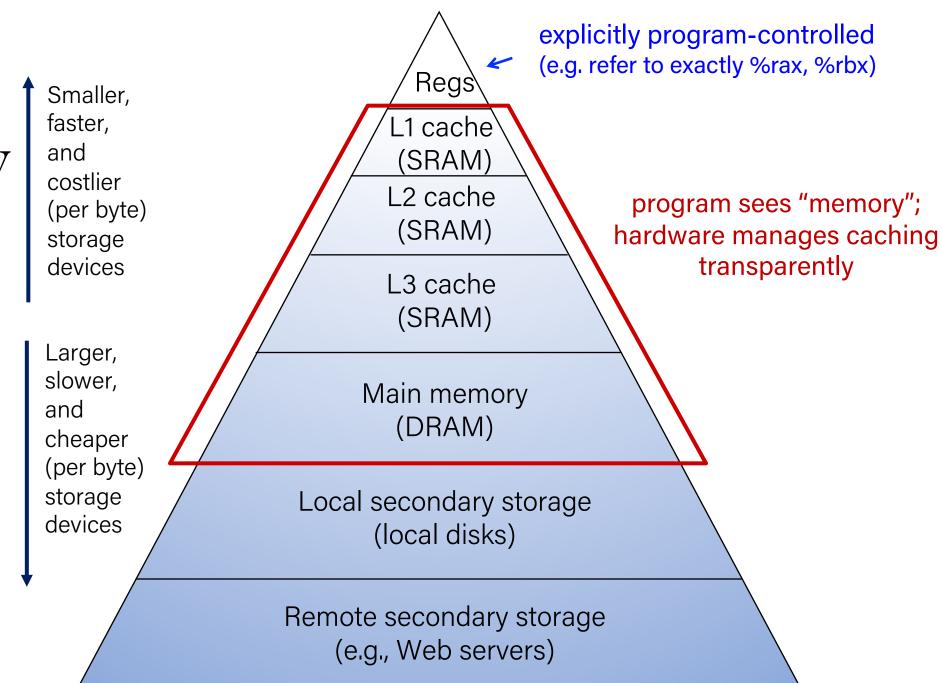
Memory Hierarchies

- Some fundamental and enduring properties of hardware and software:
 - Fast storage technologies cost more per byte, have less capacity, and require more power (heat!).
 - The gap between CPU and main memory speed is widening.
 - True for: registers ↔ cache, cache ↔ DRAM, DRAM ↔ disk, etc.
 - Well-written programs tend to exhibit good locality.
- These fundamental properties complement each other beautifully.
- They suggest an approach for organizing memory and storage systems known as a **memory hierarchy**.
 - For each level k, the faster, smaller device at level k serves as a cache for the larger, slower device at level k+1

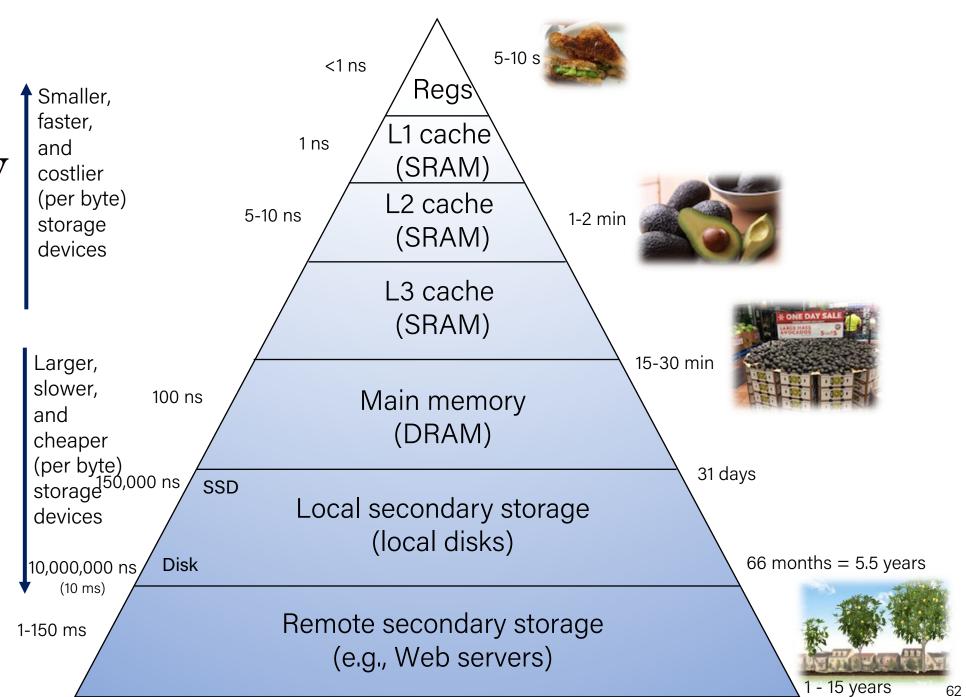
Example Memory Hierarchy



Example Memory Hierarchy



Example Memory Hierarchy



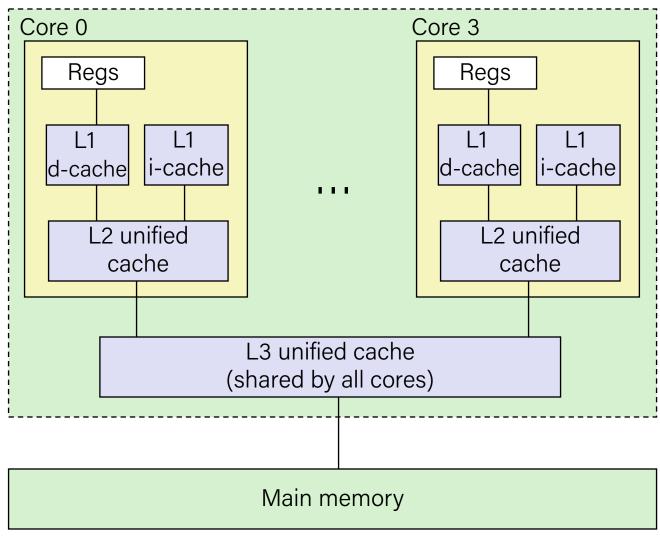
Caches

- Cache: A smaller, faster storage device that acts as a staging area for a subset of the data in a larger, slower device.
- Fundamental idea of a memory hierarchy:
 - For each k, the faster, smaller device at level k serves as a cache for the larger, slower device at level k+1.
- Why do memory hierarchies work?
 - Because of locality, programs tend to access the data at level k more often than they access the data at level k+1.
 - Thus, the storage at level k+1 can be slower, and thus larger and cheaper per bit.

Big Idea: The memory hierarchy creates a large pool of storage that costs as much as the cheap storage near the bottom, but that serves data to programs at the rate of the fast storage near the top.

Intel Core i7 Cache Hierarchy

Processor package



L1 i-cache and d-cache:

32 KB, 8-way,

Access: 4 cycles

L2 unified cache:

256 KB, 8-way,

Access: 10 cycles

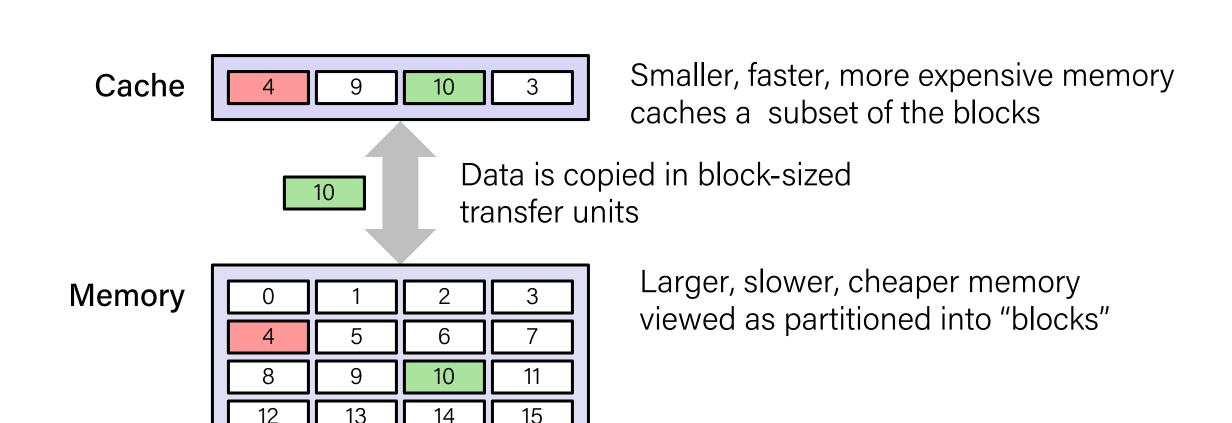
L3 unified cache:

8 MB, 16-way,

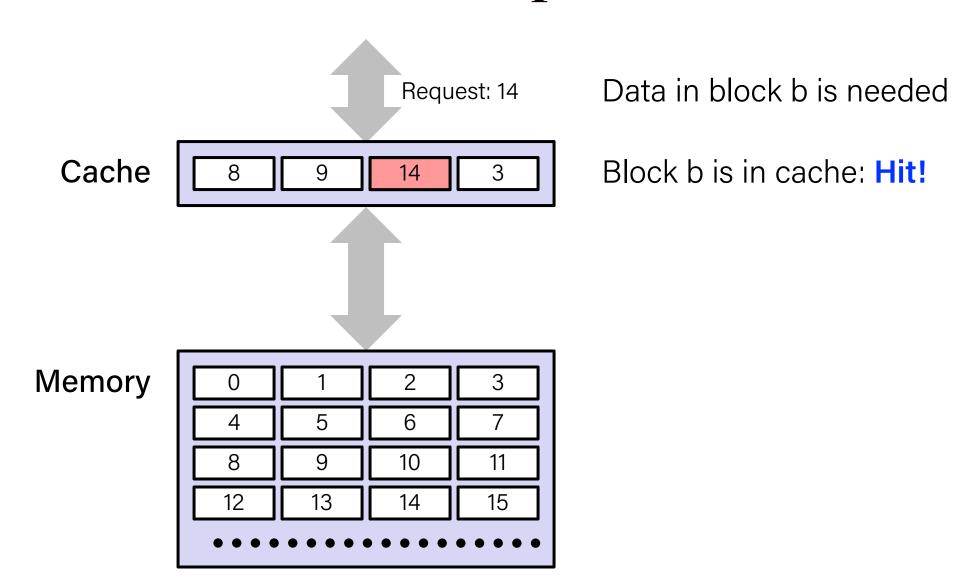
Access: 40-75 cycles

Block size: 64 bytes for all caches.

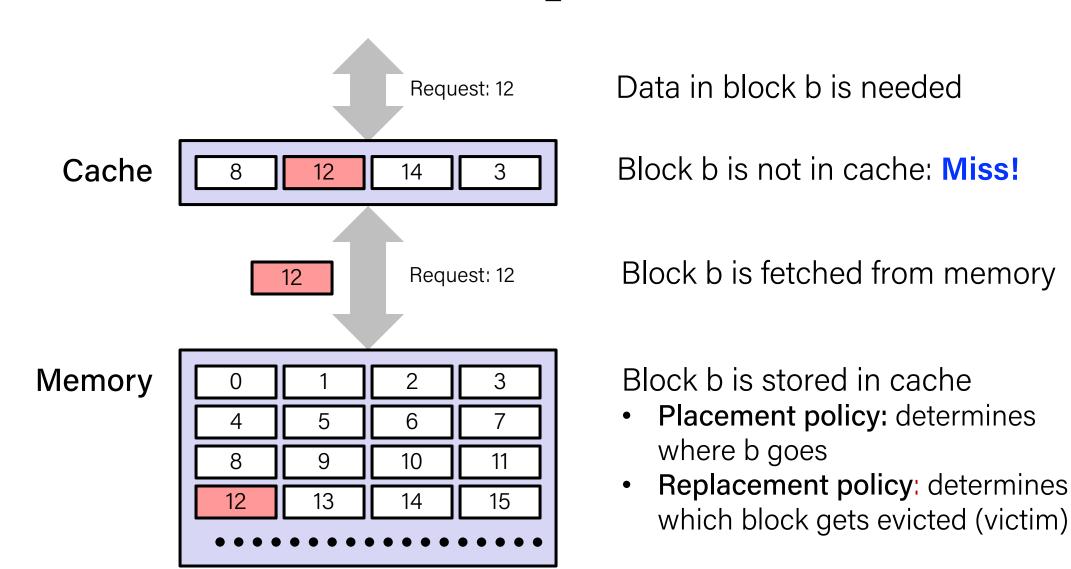
General Cache Concepts



General Cache Concepts: Hit



General Cache Concepts: Miss



Examples of Caching in the Mem. Hierarchy

Cache Type	What is Cached?	Where is it Cached?	Latency (cycles)	Managed By
Registers	4-8 bytes words	CPU core	0	Compiler
TLB	Address translations	On-Chip TLB	0	Hardware MMU
L1 cache	64-byte blocks	On-Chip L1	4	Hardware
L2 cache	64-byte blocks	On-Chip L2	10	Hardware
Virtual Memory	4-KB pages	Main memory	100	Hardware + OS
Buffer cache	Parts of files	Main memory	100	OS
Disk cache	Disk sectors	Disk controller	100,000	Disk firmware
Network buffer cache	Parts of files	Local disk	10,000,000	NFS client
Browser cache	Web pages	Local disk	10,000,000	Web browser
Web cache	Web pages	Remote server disks	1,000,000,000	Web proxy server

Summary

- The speed gap between CPU, memory and mass storage continues to widen.
- Well-written programs exhibit a property called locality.
- Memory hierarchies based on caching close the gap by exploiting locality.
- Flash memory progress outpacing all other memory and storage technologies (DRAM, SRAM, magnetic disk)
 - Able to stack cells in three dimensions

Recap

- Storage technologies and trends
- Locality of reference
- Caching in the memory hierarchy

Next: Cache memories